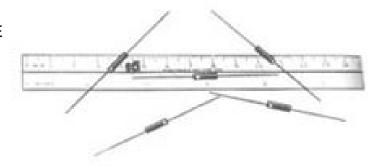


FAST RECOVERY HIGH VOLTAGE 25mA MINIATURE SILICON RECTIFIERS

- SMALL SIZE MOLDED PACKAGE
- PRV 3,000 TO 12,000 VOLTS
- 1.0 INCH MIN. LEADS
- LOW LEAKAGE



| EDI Type | PRV Volts |
|-------------|--------------|
| DL300 | 3,000 |
| DL500 | 5,000 |
| DL800 | 8,000 |
| DL1000 | 10,000 |
| DL1200 | 12,000 |

ELECTRICAL CHARACTERISTICS (at T_A = 25 °C Unless Otherwise Specified)

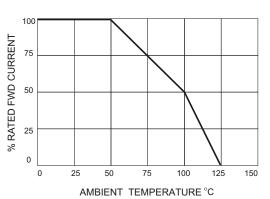
| Average Rectified Forward Current @ 50°C, Io | 25 mA |
|---|------------------|
| Max. Peak Surge Current, I _{FSM} (8.3ms) | 3 Amp |
| Max. Reverse Recovery T _{rr} (Fig.4) | 150nanosec |
| Max.Forward Voltage Drop@25mA, V _F | 26Volts |
| Max. DC Reverse Current @ PRV and 25°C, I _R | 1 μΑ |
| Max. DC Reverse Current @ PRV and 100°C, I _R | 25 μΑ |
| Ambient Operating Temperature Range, T _A | -55°C to +125 °C |
| Storage Temperature Range, T _{STG} | -55°C to +150 °C |

NOTES:

- 1.It is recommended that a proper heat sink be used on the terminals of this device between the body and soldering point to prevent damage from excess heat.
- 2.If operated over 10,000v/inch in length, devices should be immersed in oil or ree ncapsulated.

EDI reserves the right to change these specifications at any time without notice.

FIG.1 OUTPUT CURRENT vs AMBIENT TEMPERATURE



NON-REPETITIVE SURGE CURRENT 1.0SEC 100 MAXIMUM SURGE 25 25 0 30 40 50 60 3 4 5 6 7 8 9 10 CYCLES(60 Hz)

FIG.2

FIG.3 **MECHANICAL**

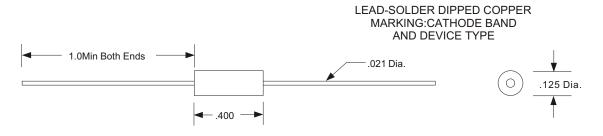
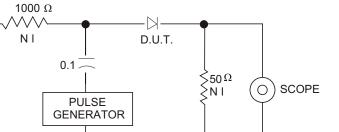


FIG.4 REVERSE RECOVERY TEST METHOD

RECOVERY WAVE FORM

T_{rr} I_{F=2MA} I_{RR=1}MA I_{R=5MA} WAVE FORMS



RECOVERY WA VE FORM

CIRCUIT

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